VS-HFA140FA120

Vishay Semiconductors



HEXFRED[®] Ultrafast Soft Recovery Diode, 140 A



| PRIMARY CHARACTERISTICS | | | | |
|-------------------------------------|----------------|--|--|--|
| V _R | 1200 V | | | |
| V _F (typical) | 2.8 V | | | |
| t _{rr} (typical) | 48 ns | | | |
| $I_{F(DC)}$ at T_C , per module | 140 A at 74 °C | | | |
| $I_{F(AV)}$ at T_{C} , per module | 140 A at 46 °C | | | |
| Package | SOT-227 | | | |

FEATURES

- Fast recovery time characteristic
- Electrically isolated base plate
- Large creepage distance between terminal
- · Simplified mechanical designs, rapid assembly
- Designed and qualified for industrial level
- UL approved file E78996
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

The dual diode series configuration VS-HFA140FA120 is used for output rectification or freewheeling/clamping operation and high voltage application.

The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

These modules are intended for general applications such as HV power supplies, electronic welders, motor control and inverters.

| ABSOLUTE MAXIMUM RATINGS | | | | |
|--|-----------------------------------|---------------------------------------|-------------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MAX. | UNITS |
| Cathode to anode voltage | V _R | | 1200 | V |
| Continuous forward current per leg | I_ | I _F T _C = 74 °C | 70 | |
| per module | ١F | | 140 | А |
| Single pulse forward current | I _{FSM} | T _J = 25 °C | 350 | |
| Maximum power dissipation, per leg | PD | T _C = 25 °C | 357 | W |
| Maximum power dissipation, per leg | FD | T _C = 100 °C | 143 | vv |
| RMS isolation voltage | VISOL | Any terminal to case, t = 1 minute | 2500 | V |
| Operating junction and storage temperature range | T _J , T _{Stg} | | -55 to +150 | °C |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | |
|--|-----------------|---|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Cathode to anode breakdown voltage | V _{BR} | I _R = 100 μA | 1200 | - | - | |
| Forward voltage, per leg | | I _F = 60 A | - | 2.8 | 4.0 | v |
| | V _{FM} | I _F = 120 A | - | 3.6 | 5.3 | |
| | | I _F = 60 A, T _J = 125 °C | - | 2.7 | - | |
| | | I _F = 60 A, T _J = 150 °C | - | 2.65 | - | |
| Reverse leakage current, per leg | I _{RM} | V _R = V _R rated | - | 2.0 | 75 | μA |
| | | $T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$ | - | 1.6 | 5 | mA |
| | | $T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$ | - | 5 | 10 | ША |

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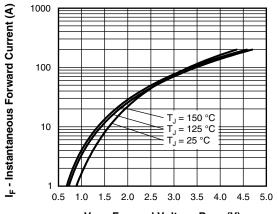


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| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified) | | | | | | | |
|---|-------------------------|---|---|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| | | $I_F = 1 \text{ A}; \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}; V_R = 30 \text{ V}$ | | - | 48 | - | |
| Reverse recovery time, per leg | t _{rr} | T _J = 25 °C | | - | 145 | - | ns |
| | | T _J = 125 °C | | - | 218 | - | |
| Peak recovery current, per leg | | $T_J = 25 \ ^\circ C$ | l _F = 50 A dl _F /dt = - 200 A/μs | - | 13 | - | A |
| Feak recovery current, per leg | IRRM | T _J = 125 °C | $V_{\rm R} = 200 \text{ V}$ | - | 18 | - | ~ |
| Poveres resource shares per les | | T _J = 25 °C | v _R – 200 v | - | 910 | - | nC |
| Reverse recovery charge, per leg Q _{rr} | T _J = 125 °C | | - | 1920 | - | nc | |
| Junction capacitance, per leg | CT | V _R = 1200 V | | - | 27 | - | pF |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|---|-------------------|-----------------------|------|------|------------|-------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Junction to case, single leg conducting | D | | - | - | 0.35 | |
| Junction to case, both legs conducting | R _{thJC} | | - | - | 0.175 | °C/W |
| Case to heatsink | R _{thCS} | Flat, greased surface | - | 0.05 | - | |
| Weight | | | - | 30 | - | g |
| Mounting torque | | Torque to terminal | - | - | 1.1 (9.7) | Nm (lbf.in) |
| Mounting torque | | Torque to heatsink | - | - | 1.8 (15.9) | Nm (lbf.in) |
| Case style | | | | S | OT-227 | |



V_{FM} - Forward Voltage Drop (V)

Fig. 1 - Typical Forward Voltage Drop Characteristics

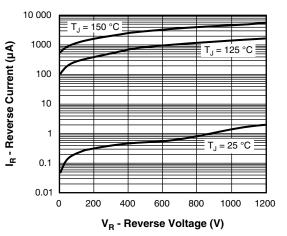
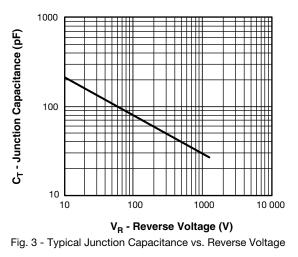
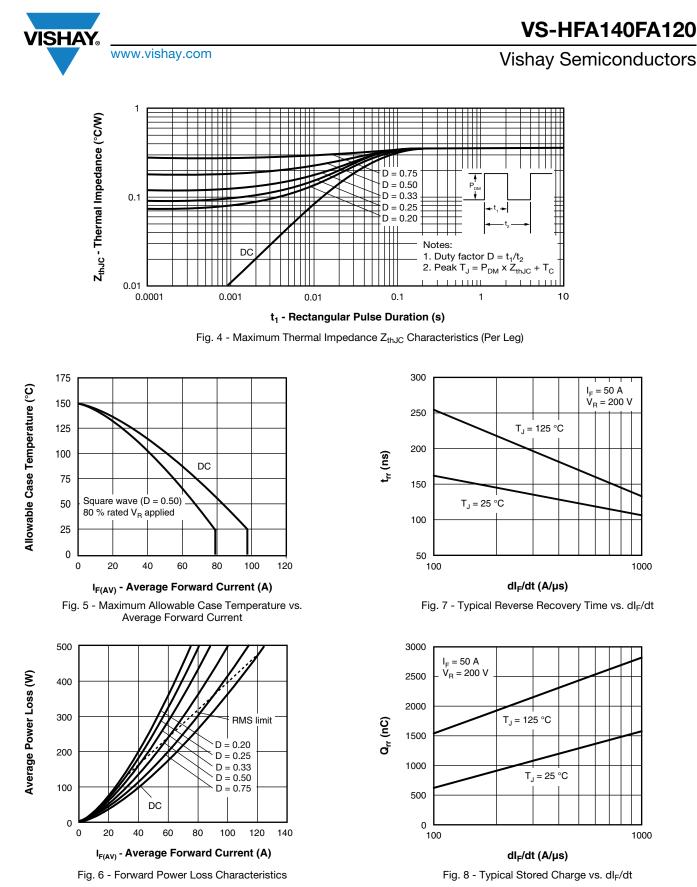


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 5); Pd_{REV} = inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = rated V_R

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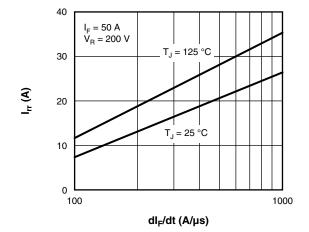


Fig. 9 - Typical Peak Recovery Current vs. dI_F/dt

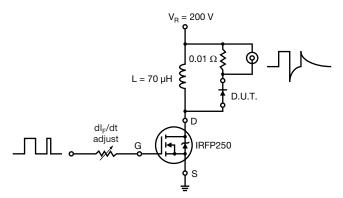


Fig. 10 - Reverse Recovery Parameter Test Circuit

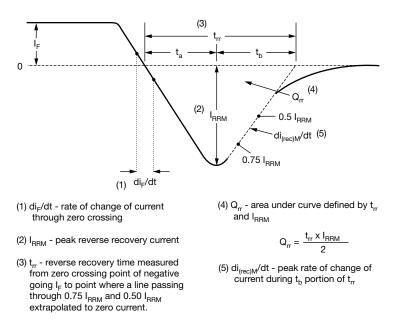


Fig. 11 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

VS-HF F **Device code** Α 140 120 Α (2)(3) 5 (6)1 (4)7 1 2 3 4 5 Vishay Semiconductors product HEXFRED[®] family Process designator (A = electron irradiated) Average current (140 = 140 A) Circuit configuration (two separate diodes, parallel pin-out) 6 Package indicator (SOT-227 standard insulated base) 7 Voltage rating (120 = 1200 V)

| CIRCUIT CONFI | CIRCUIT CONFIGURATION | | | | | |
|--|-------------------------------|-----------------|--|--|--|--|
| CIRCUIT | CIRCUIT CONFIGURATION CODE | CIRCUIT DRAWING | | | | |
| Two separate diodes, parallel pin-out | F | Lead Assignment | | | | |

| LINKS TO RELATED DOCUMENTS | | | |
|----------------------------|--------------------------|--|--|
| Dimensions | www.vishay.com/doc?95423 | | |
| Part marking information | www.vishay.com/doc?95425 | | |



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